

Far-infrared optical conductivity of CeCu_2Si_2

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Abstract.

[Journal ref.: J. Phys.: Condens. Matter **25**, 065602 (2013)] We investigated the optical reflectivity of the heavy-fermion metal CeCu_2Si_2 in the energy range 3 meV – 30 eV for temperatures between 4K – 300K. The results for the charge dynamics indicate a behavior that is expected for the formation of a coherent heavy quasiparticle state: Upon cooling the spectra of the optical conductivity indicate a narrowing of the coherent response. Below temperatures of 30 K a considerable suppression of conductivity evolves below a peak structure at 13 meV. We assign this gap-like feature to strong electron correlations due to the 4*f*-conduction electron hybridization.

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1. Introduction

The investigation of the optical properties of heavy fermion metals with 4*f*-electrons is focussed on the charge dynamics in the far- and mid-infrared energy region where the electronic structure is strongly influenced by a weak hybridization of localized *f*-electrons with conduction electrons. The relevant energy scales involved are determined by the Kondo interaction, leading to a strongly enhanced density of states at the Fermi level and the concomitant formation of heavy quasiparticle masses. A heavy fermion state arises upon the formation of coherence among heavy quasiparticles below a lattice coherence temperature. The latter has been shown to be characteristic for the temperature dependence of the far-infrared optical response in heavy fermion compounds like YbRh_2Si_2 and YbIr_2Si_2 [1, 2, 3]. The signature of the Kondo interaction itself was discussed in terms of a gap-like suppression in the far-infrared optical conductivity due to a conductionband (*c*)-*f* electron hybridization. This suppression appears at temperatures below the Kondo temperature and is related to heavy fermion properties determining, for instance, the thermodynamics. Furthermore, the strength of the *c*-*f* hybridization is reflected in a broad mid-infrared peak in the range 0.1 – 0.3 eV at low temperatures [4]. It was shown that a dynamical mean-field approach could capture these *c*-*f* hybridization features in the far-infrared region (where several maxima depending on the complexity of the hybridization could appear) as well as in the mid-infrared region [5, 6].

Although CeCu_2Si_2 is one of the most investigated heavy-fermion compounds [7] yet, to the best of our knowledge, it does not belong to the large number of correlated electron materials whose optical properties were reported [8]. Here we report optical investigations of CeCu_2Si_2 down to energies of 3 meV and temperatures down to 4 K. This allowed us to obtain yet inaccessible information on the low-energy heavy-fermion optical response of CeCu_2Si_2 .

2. Experimental

We have measured the optical reflectivity $R(\omega)$ at a near-normal angle of incidence on a single crystal of CeCu_2Si_2 . The crystal was well characterized in its thermodynamic, transport and magnetic properties and shows superconductivity below $T_C = 0.65$ K as well as antiferromagnetic order below $T_N = 0.6$ K ("S/A-type" crystal) [9]. Those properties below 1 K do not affect the transport properties at higher temperatures, hence the DC (zero energy) electrical resistivity ρ_{DC} shows the typical temperature dependence for all types of CeCu_2Si_2 samples, namely the presence of two maxima, one at 20 K due to the onset of quasiparticle coherence and one at 115 K being due to the Kondo scattering at a quasi-quartet crystalline electric field level [9]. The direction of the crystalline *c*-axis (tetragonal ThCr_2Si_2 structure) was pointing by an angle of $15 \pm 6^\circ$ out of the optically investigated crystal surface. The well polished ($0.3 \mu\text{m}$ grain) crystal was mounted behind a circular aperture with a diameter of 5 mm.

A rapid-scan Fourier spectrometer of Michelson and Martin-Puplett type was used for photon energies $\hbar\omega$ between of 0.01–1.5 eV and 3–30 meV, respectively, at sample temperatures between 4–300 K. $R(\omega)$ was extracted from two measurements: the first one measuring the sample and the second one measuring the sample after coating it *in-situ* with gold. Synchrotron radiation extended the energy range from 1.2 eV up to 30 eV for $T = 300$ K [10]. Using Kramers-Kronig relations, we calculated the optical conductivity $\sigma(\omega)$ from $R(\omega)$. The $R(\omega)$ spectra were extrapolated below 3 meV with the low-energy limit of the Drude model $R(\omega) = 1 - (2\omega\rho_{\text{DC}}/\pi)^{1/2}$ (Hagen-Rubens behavior) and above 30 eV with a free-electron approximation $R(\omega) \propto \omega^{-4}$ [11].

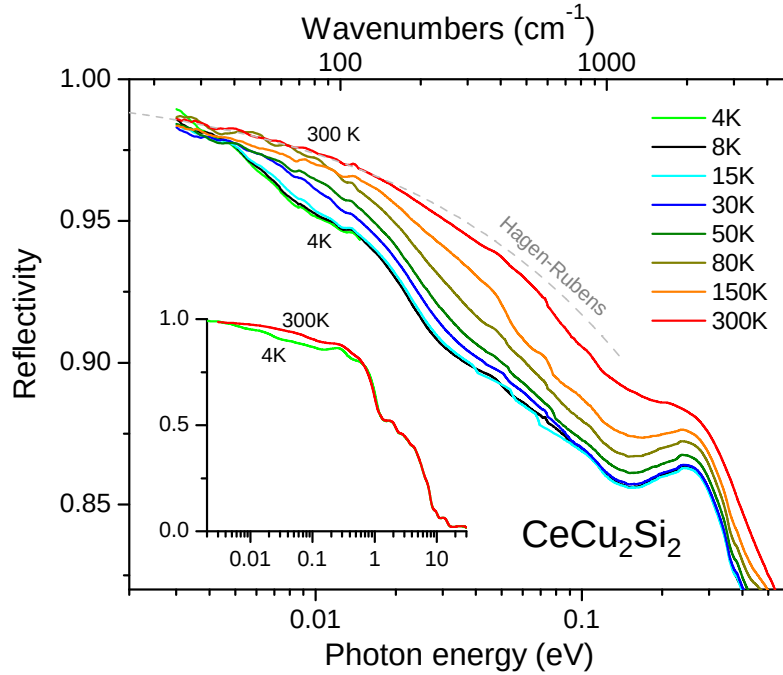


Figure 1. (Color online) Temperature dependence of the reflectivity spectrum $R(\omega)$. Dashed line shows Hagen-Rubens behavior according to a DC resistivity of $70 \mu\Omega\text{cm}$. Inset: $R(\omega)$ at 4 and 300 K in the complete accessible range of photon energies up to 30 eV.

3. Results and Discussion

The temperature dependence of the $R(\omega)$ spectra of CeCu_2Si_2 is shown in Fig. 1. The continuous increase of $R(\omega)$ towards low energies indicates the response of the conduction band. The dashed line shows a Hagen-Rubens behavior with $\rho_{\text{DC}}^{300\text{K}} = 70 \mu\Omega\text{cm}$ (in good agreement with the measured absolute value of $\rho_{\text{DC}}(T)$ [9, 12]) providing a reasonably well description of the low-energy data. However, inspecting the temperature evolution of $R(\omega)$ typical metallic behavior is seen only for $\omega \lesssim 5$ meV

and below $T \lesssim 30$ K. This peculiarity is often reported for heavy fermion metals and is discussed in terms of a renormalization of the coherent Drude response [8].

Fig. 2(a) shows the temperature dependence of the optical conductivity $\sigma(\omega)$ below 1 eV where the charge dynamics is characterized by a pronounced temperature dependence. Between the lowest accessible energy of 3 meV and 150 meV, $\sigma(\omega)$ shows a continuous decrease with decreasing temperature. As shown in Fig. 2(b), this energy range is characterized by the formation of a heavy plasma mode. For heavy-fermion

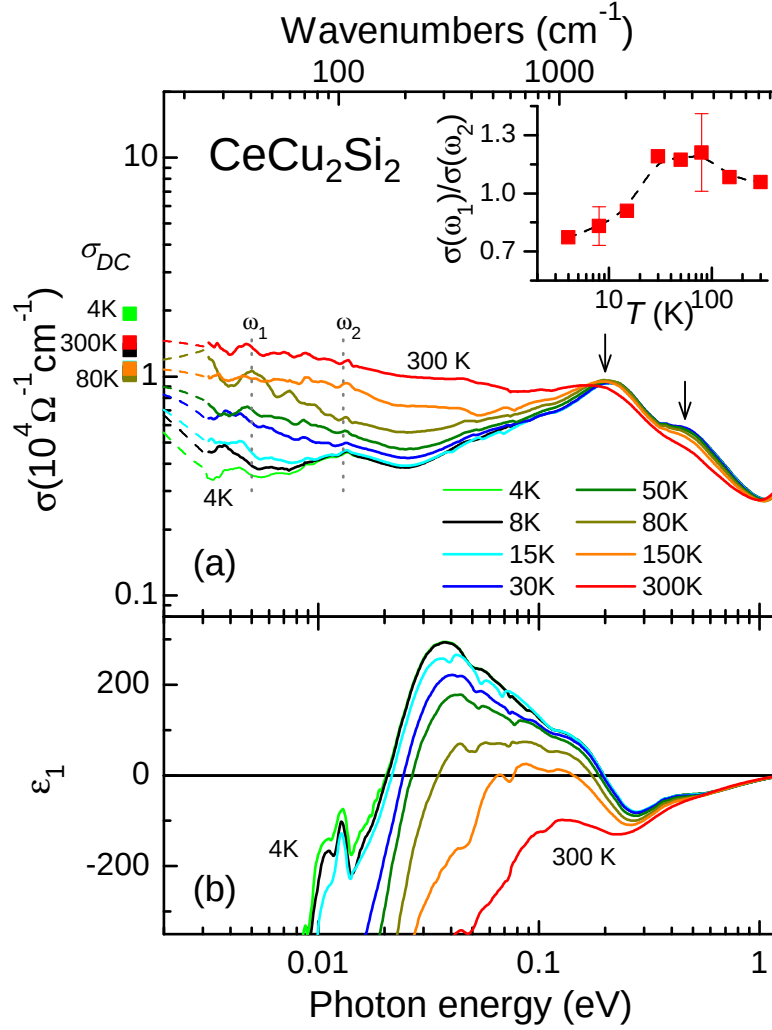


Figure 2. (Color online) (a) Temperature dependence of the optical conductivity $\sigma(\omega)$ with corresponding direct current conductivity (symbols: σ_{DC} - values at zero energy). Arrows: typical signatures related to the c - f hybridization strength in Ce- and Yb- heavy-fermion compounds. Inset: Temperature dependence of $\sigma(\omega)$ at 5 meV normalized to the 13 meV values (dashed line guides the eyes; error bars, being representative for different temperature ranges, result from experimental accuracies of $\sigma_1(\omega_{1,2})$). (b) Real part of the complex dielectric function $\epsilon_1(\omega)$ revealing the heavy plasmon energy from zero-crossings.

compounds, in the low-temperature coherent state, the real part of the complex dielectric function, $\varepsilon_1(\omega)$, is expected to show two zero-crossings from negative to positive. The crossing at lower energy (ω_p^*) is associated with heavy plasmons, the one at higher energy with the plasma energy of uncorrelated electrons [13]. Such analysis of $\varepsilon_1(\omega)$ was considered, for instance, for $CeAl_3$ [14] or for the Ce-115 system [15]. For $CeCu_2Si_2$, see Fig. 2(b), the heavy plasma mode ω_p^* develops already at ≈ 150 K and reaches values down to about 20 meV for 4 K. Since the effective mass m^* is proportional to $1/\omega_p^{*2}$, m^* at 4 K is about ten times larger than that at 150 K. The plasma energy for the uncorrelated electrons is located at ≈ 1.5 eV.

Additional information on the heavy fermion optical response and its relation to the Kondo interaction can be inferred from the behavior of $\sigma(\omega)$ at the lowest energies. Interestingly, for $T < 30$ K $\sigma(\omega)$ shows an additional suppression in the region around $\omega_1 = 5$ meV and a concomitant evolution of a peak structure at $\omega_2 \approx 13$ meV, i.e. a gap-like feature appears. As illustrated in the inset this feature shows a temperature dependence which we estimated by using the temperature evolution of $\sigma(\omega_1)/\sigma(\omega_2)$. The overall temperature behavior of this ratio does not depend on the exact choice of ω_1 and ω_2 . From 300 K down to 30 K $\sigma(\omega_1)/\sigma(\omega_2)$ shows a continuous increase reflecting a continuous decrease of the scattering rate of the low-energy Drude part. Below 30 K, towards lower temperatures, a strong decrease of $\sigma(\omega_1)/\sigma(\omega_2)$ demonstrates the gap opening resulting in an additional suppression of $\approx 25\%$ for $\sigma(\omega_1)$ at the lowest temperature. Note, that in this temperature regime also the Kondo effect with $T_K = 10$ K should influence the charge dynamics, suggesting a relation of this gap to the presence of $4f$ electrons. Hence, we attribute the suppression of $\sigma(\omega)$ below 13 meV to the opening of a hybridization gap which arises from the weak hybridization of the $4f$ states with the conduction electron band states as a consequence of the Kondo interaction.

The properties of the peak structure at around 13 meV are similar to those observed in other $4f$ -based correlated electron systems, notably in the Kondo-semiconductors YbB_{12} [16] or $CeFe_2Al_{10}$ [17], the intermediate valent system $YbAl_3$ [18], and in the heavy-fermion systems $YbRh_2Si_2$ and $YbIr_2Si_2$ [2]. For the skutterudite heavy-fermion system $CeRu_4Sb_{12}$ a peak of similar type is not reported with comparable clarity [19] whereas in certain Ce-based Kondo semiconductors comparable structures were discussed in terms of a pseudogap opening in the heavy quasiparticle band [20]. $CeCu_2Si_2$ seems to be the first example of a Ce-based heavy-fermion compound where such a clear gap opening in the vicinity of the Kondo temperature is observed.

The peak and shoulder structures at around 0.2 eV and 0.45 eV (indicated by arrows in Fig. 2(a)) correspond to those typically found in a variety of Ce- and Yb-heavy fermion compounds. It was shown that their peak energies universally scale with the c - f hybridization strength [4].

The discussed signatures of strong electron correlations can be supplemented by a consideration of the energy dependence of the spectral weight which is determined by

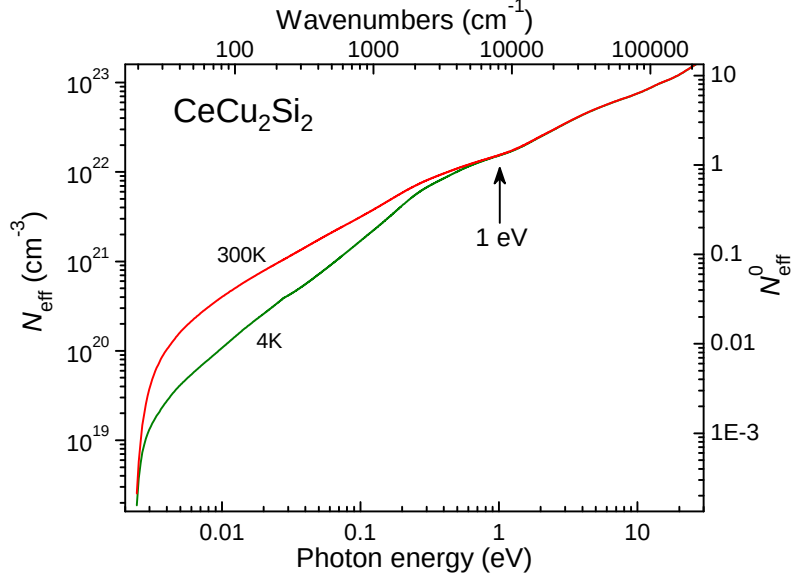


Figure 3. (Color online) Effective charge carrier density N_{eff} (from Eq.1) which contributes to optical excitations at a given energy. Below energies of ≈ 1 eV a pronounced loss of spectral weight is visible upon cooling from 300 K to 4 K. Right axis shows $N_{\text{eff}}^0 = N_{\text{eff}} \cdot V_0/2$ per formula unit using the unit cell volume $V_0 = 1.6695 \cdot 10^{-22} \text{cm}^3$.

the effective charge carrier density N_{eff} :

$$N_{\text{eff}}(\omega) = \frac{2m_0}{\pi e^2} \int_0^\omega \sigma_1(\omega') d\omega' \quad (1)$$

with m_0 the free-electron mass. As shown in Fig. 3 N_{eff} becomes temperature independent for energies larger than 1 eV. This points to a correlation effect [21] because it indicates a redistribution of spectral weight up to energies much larger than the hybridization gap energy of 13 meV which characterizes the low-temperature optical response of the heavy quasiparticles.

4. Conclusion

The optical conductivity of the heavy-fermion metal CeCu_2Si_2 shows features typical for a heavy electron optical response. At the lowest accessed temperature of $T = 4$ K and the lowest energy of 3 meV signatures of the tail of a renormalized Drude peak could be observed. This is suggested by a energy dependent suppression of the optical conductivity with decreasing temperature, indicating the effect of strong electron correlations. We identified a correlation induced hybridization gap which forms below about 13 meV and for temperatures below about 30 K. This agrees with the characteristic energy of the $4f$ -conduction electron interaction in CeCu_2Si_2 with a Kondo temperature of 10 K. The strongly temperature dependent gap formation in the optical conductivity leads to a transfer of spectral weight toward energies up to 1 eV.

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